NSN 5962-01-351-9029

Memory Microcircuit - Page 1 of 1



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Body Length:
1.060 inches
Body Width:
0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
2.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and bipolar and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
12.0 volts input
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, high to low level output and 50.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Pal
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0